

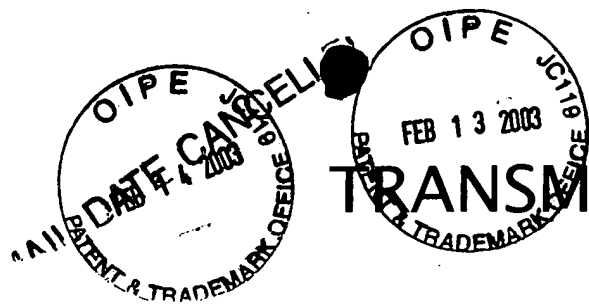
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Electronic Patent Application Submission
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EFS ID: 23230
Application ID: 09955641
Title of Invention: SEMICONDUCTOR MEMORY CELL
AND MEMORY ARRAY USING A
BREAKDOWN PHENOMENA IN AN
ULTRA-THIN DIELECTRIC
First Named Inventor: Jack Peng
Domestic/Foreign Application: Domestic Application
Filing Date: 2001-09-18
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Attorney Docket Number: 384848001US
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Trademark Office, ou=Department of Commerce, o=U.S.
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Submission Type: Information
Disclosure Statement

Application Number: 09/955,641
Attorney Docket Number: 384848001US

SEMICONDUCTOR MEMORY CELL AND MEMORY ARRAY USING A BREAKDOWN PHENOMENA IN AN ULTRA-THIN DIELECTRIC

First Named Inventor: Jack Zezhong Peng

SUBMITTED BY

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Attached Files:

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Electronic Information Disclosure Statement

SEMICONDUCTOR MEMORY CELL AND MEMORY ARRAY USING A BREAKDOWN PHENOMENA IN AN ULTRA-THIN DIELECTRIC

Application:



09/955641

Confirmation:

1777

Applicant(s):

Jack Peng

Docket Number:

384848001.US

Group Art Unit:

2824

Examiner:

Hien N. Nguyen

search string:

(4677742 or 4599705).pn.

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US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

init	Citation No.	Patent Number	Date	Bar Code	Patentee	Class	Subclass
	P01	4677742	1987-07-07		Johnson	29	591
	P02	4599705	1986-07-08		Holmberg et al.	365	163

Signature

Examiner Name	Date